

Solving the Cable Equation Using a Compact Difference Scheme - Passive Soma Dendrite

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Abstract

Dendrites are extensions to the neuronal cell body in the brain which are posited in several functions ranging from electrical and chemical compartmentalization to coincident detection. Dendrites vary across cell types but one common feature they share is a branched structure. The cable equation is a partial differential equation that describes the evolution of voltage in the dendrite. A solution to this equation is normally found using finite difference schemes. Spectral methods have also been used to solve this equation with better accuracy. Here we report the solution to the cable equation using a compact finite difference scheme which gives spectral like resolution and can be more easily used with modifications to the cable equation like nonlinearity, branching and other morphological transforms. Widely used in the study of turbulent flow and wave propagation, this is the first time it is being used to study conduction in the brain. Here we discuss its usage in a passive, soma dendrite construct. The superior resolving power of this scheme compared to the central difference scheme becomes apparent with increasing complexity of the model.

Keywords

dendrites, cable equation, passive soma-dendrite, numerical methods, spectral methods, finite difference scheme, compact difference scheme

Introduction

The *cable equation* governs the dynamics of membrane potential in thin and long cylinders such as axons or dendrites in neurons. It is Wilfred Rall's derivation of the cable equation which set the ground for describing quantitatively the change in voltage across space and time in dendrites [1–3]. Under consideration here is a linear system involving neuronal processes that have a voltage independent component. The model is a *passive* one which means that membrane conductance is fixed. Here we only look at *subthreshold responses* which are about half the strength required to generate action potentials. If the response is stronger the membrane potential will begin to change and our assumption of *passive dendrite*

will no longer be true. The cable equation is ([2], equation 2.7)

$$\frac{\tau_m \partial V_m(x, t)}{\partial t} = \frac{\lambda^2 \partial^2 V_m(x, t)}{\partial x^2} - (V_m(x, t) - V_{rest}) + r_m I_{inj}(x, t) \quad (1)$$

Here V_m is the membrane potential in mV, r_m is the membrane resistance per unit length of the fibre in $\Omega \cdot \text{cm}$. $I_{inj}(x, t)$ is the injected current in Amperes, $\tau_m = r_m c_m$ is the membrane time constant and $\lambda = (r_m/r_a)^{1/2}$ is the membrane space constant. c_m is capacitance per unit length of cable of diameter d in units of F/cm. r_a is axial resistance per unit length in Ω/cm . V_{rest} varies between -50 and -90 mV depending on cell type. Nondimensionalising this equation results in :

$$\frac{\partial V(X, T)}{\partial T} = \frac{\partial^2 V(X, T)}{\partial X^2} - V(X, T) + \frac{I(X, T)}{\lambda c_m} \quad (2)$$

Here $X = x/\lambda$, $T = t\tau$, $I(X, T) = \lambda\tau I_{inj}(x, t)$, $I_{inj}(x, t)$ is stimulus current density and $c_m = C_m \pi d$, C_m is specific capacitance/unit area in F/cm². Fig 1 shows the compartmental electrical representation of a segment of passive membrane.

Numerical method for the cable equation

Numerical analysis involves designing algorithms that approximate the solution to the equation under consideration [4]. As in all approximations, this results in a small error called the truncation error. Most finite difference schemes use the central difference formulae. It can be derived from the Taylor's series and shows algebraic convergence [5]. The second derivative $\frac{\partial^2 V}{\partial X^2}$ in equation 1, also written as V'' can be approximated as ([5], equation 8.54) :

$$V_i'' = \frac{(V_{i+1} - 2V_i + V_{i-1}))}{h^2} + O(h^2), 2 \leq i \leq N - 1 \quad (3)$$

The subscripts denote locations on a uniformly spaced grid x_i and h is the mesh size $x_{i+1} - x_i$. $O(h^2)$ is the truncation error which is second order in this case. The length L of the cable is divided into uniform segments of length $h = L/(N - 1)$ where N is the number of nodes. V_i is the voltage at location i at distance $X_i = (i - 1)h$. Indices $i = 1$ and $i = N$ denote boundary points $X = 0$ and $X = L$. Fig 2 shows this.

For spectral methods the convergence is exponentially fast [6]. The cable equation has been solved using a spectral Chebyshev method [7]. The solutions have uniform, high numerical accuracy at *any* spatial point- not just the original collocation points. The truncation error is negligible and the total error can be the roundoff error of the computations.

In this paper a compact finite difference scheme is utilized [8]. Such a scheme provides better resolution at the shorter length scales compared to the usual explicit schemes like equation 3. Thus it provides the resolution of spectral methods but unlike spectral methods which are sensitive to discontinuities, requires little extra procedure for generalisation of the governing equation (like geometry and other property variations along the dendrite).

Spatial discretisation : Using compact finite difference schemes to solve the cable equation

The second derivative $\frac{\partial^2 V}{\partial x^2}$ is approximated using the following equation ([8], equation 2.2):

$$\begin{aligned} \beta V''_{i-2} + \alpha V''_{i-1} + V''_i + \alpha V''_{i+1} + \beta V''_{i+2} &= \frac{c(V_{i+3} - 2V_i + V_{i-3})}{9h^2} \\ &+ \frac{b(V_{i+2} - 2V_i + V_{i-2})}{4h^2} \\ &+ \frac{a(V_{i+1} - 2V_i + V_{i-1})}{h^2}, 2 \leq i \leq N - 1 \end{aligned} \quad (4)$$

where V''_i represents the finite difference approximation to the second derivative at node i. The relations between the coefficients a,b,c and α , β are derived by matching the Taylor series coefficients of various orders. We take ([8],equation 2.2.7)

$$\alpha = \frac{2}{11}, \beta = 0, a = \frac{12}{11}, b = \frac{3}{11}, c = 0$$

to obtain a sixth order formula. For the boundaries the scheme chosen is ([8],equation 4.3.4)

$$V''_1 + \alpha V''_2 = \frac{aV_1 + bV_2 + cV_3 + dV_4 + eV_5}{h^2} \quad (5)$$

A similar equation connects V_N'' and V_{N-1}'' . By requiring third - order formal accuracy the coefficients are reduced to ([8],equation 4.3.6),choosing $\alpha = \frac{1}{10}$ from classical Pade scheme which is fourth order.

$$a = \frac{(11\alpha + 35)}{12}, \quad b = \frac{-(5\alpha + 26)}{3}, \quad c = \frac{(\alpha + 19)}{2}, \quad d = \frac{(\alpha - 14)}{3}$$

$$e = \frac{(11 - \alpha)}{12}$$

The truncation error is reduced to $(\frac{\alpha-10}{12})h^3V^5$. If α is 10, truncation error becomes h^4 . Equation 4 and 5 applied at interior points result in a matrix problem $\mathbf{A}V'' = \mathbf{B}$ where A is tridiagonal and V'' can be obtained easily.

Time discretisation

The values for V'' calculated from the compact-difference scheme were used to integrate the result in time using an explicit time stepping scheme - forward Euler. If $t = n\Delta T$, $V^n \equiv V(t)$ and $V^{n+1} \equiv V(t + \Delta T)$, then :

$$V^{n+1} = V^n + f(V^n, n\Delta T)\Delta T \quad (6)$$

Stability conditions have dictated the choice of the time step

$$\Delta T = \frac{\Delta x^2}{4} \quad (7)$$

It varies as shown in (Table 1).The numerical integration in time has been done with an explicit scheme. Since spatial derivatives are obtained with a compact scheme, which is an implicit formula that requires the solution of a linear system, implicit time-stepping is not possible. Implicit time-stepping is desirable to overcome the severe restrictions that stability imposes on the time-step of conditionally stable explicit schemes. A work-around is to use a predictor-corrector scheme which uses an explicit step estimate from the predictor step in a corrector step which is also an explicit step.

Computations were performed on a Toshiba Satellite Pro laptop using Octave in a Linux(Ubuntu)environment.

The data used for simulations is given in (Table 3).

Specific problems

There are four problems we have considered. Before discussing each in detail, the initial and boundary conditions used are discussed:

Initial Condition:

$$V(x, 0) = v(x), 0 \leq x \leq l \quad (8)$$

Here $v(x) = -70$ mV.

Boundary Condition:

Notation : $V'(x, t) = \frac{\partial V(x, t)}{\partial x}$

Current Injection:

If there is a current of magnitude $I(t)$ injected into the end at $x = 0$ (in the positive x- direction), ([3],equation 4.36)

$$V'(0, t) = -r_i I(t), t > 0 \quad (9)$$

If the current $I(t)$ is injected into the end at $x = l$, ([3],equation 4.37)

$$V'(l, t) = r_i I(t), t > 0 \quad (10)$$

Sealed end

If end at $x = 0$ is sealed, ([3],equation 4.32)

$$V'(0, t) = 0, t > 0 \quad (11)$$

If end at $x = l$ is sealed, ([3],equation 4.33) :

$$V'(l, t) = 0, t > 0 \quad (12)$$

Killed end

If end at $x = 0$ is killed, ([3],equation 4.34)

$$V(0, t) = 0, t > 0 \quad (13)$$

or if end at $x = l$ is killed, ([3], equation 4.35)

$$V(l, t) = 0, t > 0 \quad (14)$$

1. Point soma dendrite, current injection at $x = 0$: The point soma dendrite construct we have used is a soma (cell body) collapsed into a point as mentioned in [7] along with a dendrite attached to it (Fig. 4). The governing equation is the cable equation as mentioned above in equation 1. (Range for independent variables $0 < x < l, t > 0$ and the steady state at $t \rightarrow \infty$). Initial condition is given by equation 8. Boundary conditions are current injection at $i = 1$ (equation 9) and at $i = N$, sealed end (equation 12) or killed end (equation 14).

The analytical equation at steady state for this formulation with sealed end boundary condition at $i = N$ is ([3], Table 4.2) :

$$V(x) = V(0) \left(\frac{\text{Cosh}(L - X)}{\text{Cosh}(L)} \right) \quad (15)$$

where $V(x)$ is the voltage at any given i , $V(0)$ is the voltage at $i = 1$, $L = \frac{l}{\lambda}$, $X = \frac{x}{\lambda}$. The analytical equation at steady state for the boundary condition with killed end at $i = N$ is ([3], Table 4.2):

$$V(x) = V(0) \left(\frac{\text{Sinh}(L - X)}{\text{Sinh}(L)} \right) \quad (16)$$

where $V(x)$, $V(0)$, L and X are as defined above.

2. Lumped soma model, current injected into soma: Additionally, we have used a lumped soma model where the current is injected into the soma (Fig. 4). Here the boundary condition at $i = 1$ is a lumped soma boundary condition at steady state ([3], equation 6.14), For a first order case, this is :

$$\frac{R_s \bar{I}_s}{\tau} = \bar{V}(0) - \gamma \bar{V}'(0) \quad (17)$$

where R_s is the membrane resistance at soma, $\gamma = \frac{R_s}{r_i}$, I_s is the current injected at the soma, τ is the time constant.

The boundary condition at $i = N$ can either be sealed end (equation 12) or killed end (equation 14).

The analytical equation at steady state is ([3],equation 6.20) :

$$V(X) = IR_N \left(\frac{\text{Cosh}(L - X)}{\text{Cosh}(L)} \right) \quad (18)$$

where $V(X)$ is the voltage at any given node i , I is the injected current, $L = \frac{l}{\lambda}$, $X = \frac{x}{\lambda}$ and $\frac{1}{R_N} = \frac{1}{R_S} + \frac{1}{R_M}$ ([3],equation 6.21).

3. Point soma dendrite, current injection at $i = N$: When current is injected at the end of the dendrite at $i = N$ as shown in (Fig. 4), then according to convention longitudinal currents are positive in the positive x- direction. The equation governing this is the cable equation (1) as before with conditions given earlier. The boundary condition for current injected at the end ($i = N$) is defined by equation 10. The boundary conditions at the end ($i = 1$) can be sealed (equation 11) or killed (equation 13).

4. Point soma dendrite, current injection at $i = N/2$: Here current is injected at the point $i = N/2$ as shown in (Fig. 4)

The current injection condition is

$$I(X, T) = \lambda \tau I_{inj}(x, t), i = N/2 \quad (19)$$

$$I(X, T) = 0, i \neq N/2 \quad (20)$$

The boundary conditions at $i = 1$ can be sealed (equation 11) or killed (equation 13). Similarly the boundary conditions at $i = N$ can be sealed (equation 12) or killed (equation 14).

The aim of this paper is to solve the cable equation using the compact difference scheme. This has been achieved in the passive soma dendrite construct. To the best of our knowledge, this is the first time the compact difference scheme is being used to solve equations involving changing parameters in the brain.

Results

The results obtained in the above discussed simulations are presented here:

Point soma dendrite, current injection at $x = 0$

Current injection at $i = 1$, Evolution of voltage

In this simulation, current is injected at $i = 1$ and the evolution of voltage at various times is observed.

$$t = (\Delta T)(n)(\tau) \quad (21)$$

For $N = 30, \tau = 20$ msec, the voltage evolution is looked at t as shown in (Table 2). The results for both sealed and killed end boundary condition at $i = N$ can be seen in (Fig 5).

Current injection at $i = 1$, Comparison with analytical equation at steady state

In this simulation, current is injected at $i = 1$, $N = 30$ and the simulation is run till $t = 500$ msec. The results are compared with the analytical equation. V/V_0 is plotted against X . The results are shown in (Fig. 6).

Current injection at $i = 1$, Comparison between compact, central difference schemes with analytical equation at steady state, sealed end boundary condition

$\frac{V}{V_0}$ is plotted against X for the compact difference scheme, central difference scheme and the analytical solution for sealed end and results are shown in (Fig. 7). The second derivative $\frac{\partial^2 V}{\partial x^2}$ is approximated using equation 4. By choosing coefficients as given below, it gives fourth order accuracy. The coefficients are ([3], equation 2.2.6):

$$\beta = 0, \quad c = 0, \quad a = \frac{4(1-\alpha)}{3}, \quad b = \frac{1(-1+10\alpha)}{3}, \quad \alpha = \frac{1}{10}, \quad \alpha_1 = \frac{1}{10}$$

The equation for the fourth order central difference scheme is calculated using ([9], Table 6.4):

$$V''(i) = \frac{[-\frac{1}{12}V(i-2) + \frac{4}{3}V(i-1) - \frac{5}{2}V(i) + \frac{4}{3}V(i+1) - \frac{-1}{12}V(i+2)]}{h^2}, \quad 2 \leq i \leq N-1 \quad (22)$$

The boundaries for the central difference scheme are calculated using :

$$V''(1) = \left(\frac{4V(1+1) - 3V(1) - V(1+2)}{2h} \right) \quad (23)$$

$$V''(N) = \left(\frac{4V(N-1) - 3V(N) - V(N-2)}{2h} \right) \quad (24)$$

The points next to the boundary are calculated using :

$$V''(2) = \frac{\frac{15}{4}V(2) - \frac{77}{6}V(N-2) + \frac{107}{6}V(4) - 13V(5) + \frac{61}{12}V(6) - \frac{5}{6}V(7)}{h^2} \quad (25)$$

$$V''(N-1) = \frac{\frac{15}{4}V(N-1) - \frac{77}{6}V(N-2) + \frac{107}{6}V(N-3) - 13V(N-4) + \frac{61}{12}V(N-5) - \frac{5}{6}V(N-6)}{h^2} \quad (26)$$

where $h = \Delta x$.

Comparison of error between compact and central difference schemes, $N = 10, 20, 30, 40$

$$\%Error1 = 100 * \left| \frac{V_{comp} - V_{anal}}{V_{anal}(1)} \right| \quad (27)$$

$$\%Error2 = 100 * \left| \frac{V_{cent} - V_{anal}}{V_{anal}(1)} \right| \quad (28)$$

$\%Error1$ and $\%Error2$ are plotted against X . The results are shown in (Fig. 8).

Dependence of voltage changes on dendritic diameter

Current is injected at $i = 1$ for dendrites of various diameter and $\frac{V}{V_0}$ is plotted versus X . The results are given in (Fig. 9).

Point soma dendrite, current injection as $x = l$

Current injection at $i = N$, sealed and killed end, Evolution of voltage

The current is injected at the end opposite to the soma and the voltage evolution from $t = 0.0016969$ msec to $t = 500$ msec is plotted. The initial condition is shown in equation 8. The boundary condition at $i = 1$ is chosen to be either sealed end given by equation 11 or killed end, equation 13. The boundary condition at $i = N$ is the current injection boundary condition shown by equation 10. Results are shown in (Fig. 10).

Point soma dendrite, current injection as $x = \frac{l}{2}$

The current is injected at $i = \frac{N}{2}$. The initial condition is given by equation 8. The boundary conditions at $i = 1$ and $i = N$ can either be sealed end given by equations 11, 12 or killed end given by equations

13, 14.

Lumped soma, current injection at soma

Current injection at soma, lumped soma boundary condition, Evolution of voltage

Here the current is injected at the soma as shown in (Fig. 4) and the evolution of voltage at various times is observed.

$$t = (\Delta T)(n)(\tau) \quad (29)$$

For $N = 30, \tau = 20$ msec, the voltage evolution is looked at t as shown in (Table 2). The results for both sealed and killed end boundary conditions at $i = N$ can be seen in (Fig 5).

Discussion

It might be apt here to quote Wilfred Rall [10], 'An important basic principle of prudent research, both theoretical and experimental, is not to tackle too many complications at once. This was my reason for beginning my modeling with uniform, passive membrane, and with idealized geometry. Once you solve the reduced problem, you can then begin to deal with some of the complications judged to be functionally important.' Keeping this advice in mind, we have demonstrated here the usage of the compact difference scheme to a passive soma dendrite construct under varying experimental and morphological situations.

Our results show that the scheme is robust under all the conditions and shows a good fit with the analytical solution even at $N = 10$. By looking at the percent error $EP1$ (point soma), (Table. 4) at $N = 10$, it can be seen that it is almost the same for compact and central schemes. The error due to the central scheme is about 0.001 less than that due to the compact scheme.

Lele [8] defines resolving efficiency as a difference between the modified wavenumbers of spectral scheme and the differencing scheme. This is specific to a scheme for any given error. Thus it can be seen that at error $\epsilon \leq 0.001$, the resolving efficiency of the fourth order compact scheme is 0.22 which is greater than that of the fourth order central scheme which is 0.17. See (Table. 5). It is also seen that the resolving efficiency of the sixth order compact scheme is 0.38.

The simulations dealing with evolution of voltage show that when current is injected at

$i = 1$, the voltage evolves to a higher value for both sealed and killed end. The cable reaches a steady state faster for the killed end than the sealed end. This is to be expected as there is no leakage at the sealed boundary. In the lumped soma case, the voltage reached at steady state is less than that at the point soma. This could be due to the R-C circuit comprising the lumped soma which results in some current injected going to charge this resulting in a smaller value of current flowing through the cable. The shape of the voltage evolution when current is injected at $i = N$ (point soma) is different for both sealed and killed end and it also evolves to a lesser voltage at steady state than current injection at $i = 1$. The rate of evolution is also much slower in this case. Finally, when current is injected at $i = \frac{N}{2}$, the resulting plots show predictable curves expected when either both ends are sealed or killed.

As λ is directly proportional to the square root of the diameter of the dendrite, one can see that as the diameter increases (Fig 9), the lambda increases too and the plots for both sealed and killed end boundaries give expected results. See (Table. 6)

The numerical integration under consideration is an explicit scheme. In compact schemes, explicit schemes can only be used. This is unlike central schemes where both explicit and implicit techniques can be used. In the compact scheme used here, the stability is linked to ΔT or the time step that is being used. Various values of ΔT used are shown in (Table 1). It is observed that this results in slower computations.

In the simple cable chosen here, it is not possible to see the spatial resolving efficiency of the compact scheme. It is expected that the spatial resolving power of the compact scheme can be viewed with greater complexity of the model and also by choosing schemes with different coefficients than the sixth order tridiagonal scheme chosen here. From Lele [8] it can be seen that an eighth order tridiagonal scheme can yield at $\epsilon \leq 0.001$, a resolving efficiency of 0.48 and a spectral like pentadiagonal scheme can yield a resolving efficiency of 0.84.

In this paper, it has been shown that the compact scheme can be used to solve the cable equation under various morphological and experimental conditions. Ongoing work looks at the use of this tool in the case of branched, tapered and active dendrites where the complex geometry could yield situations where the compact scheme is more efficient.

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Figure

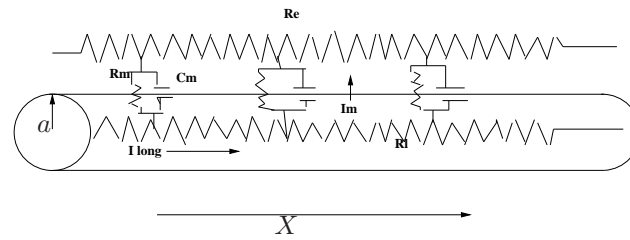


Figure 1. Compartmental electrical representation of a segment of passive cable

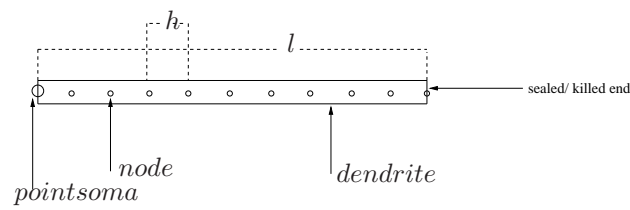


Figure 2. Discretisation of a dendritic tree

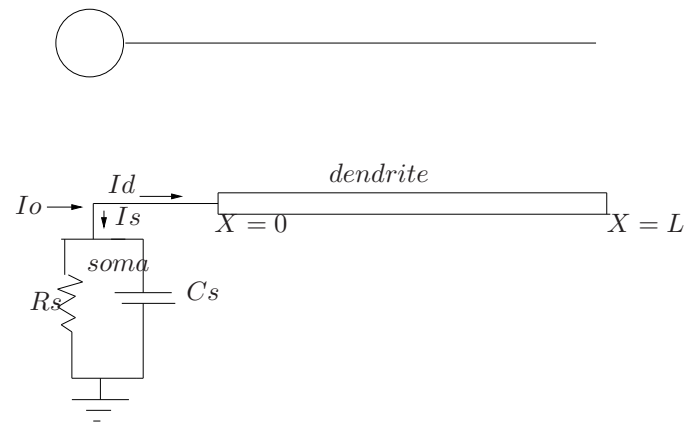


Figure 3. Dendrite with lumped soma

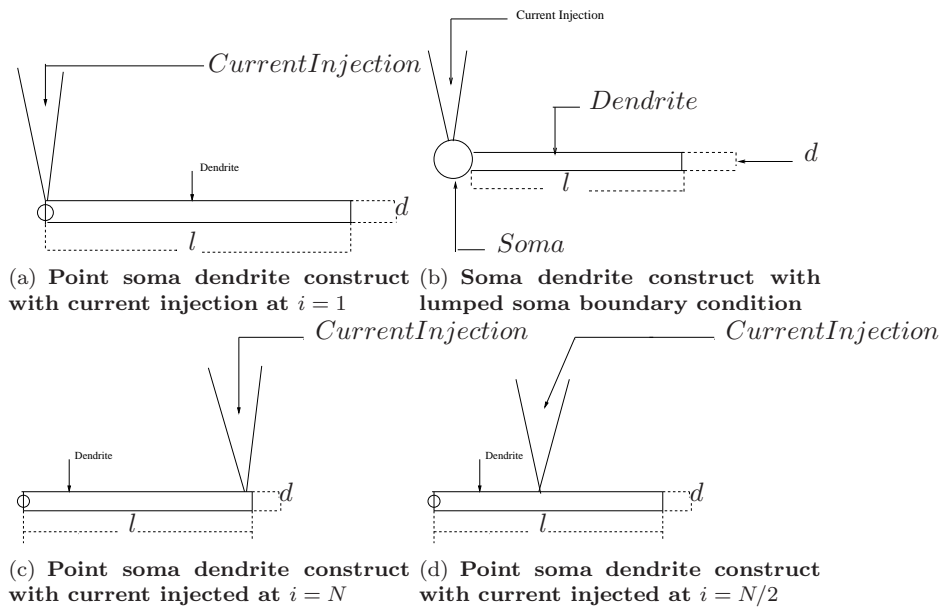


Figure 4. Soma dendrite construct - different cases

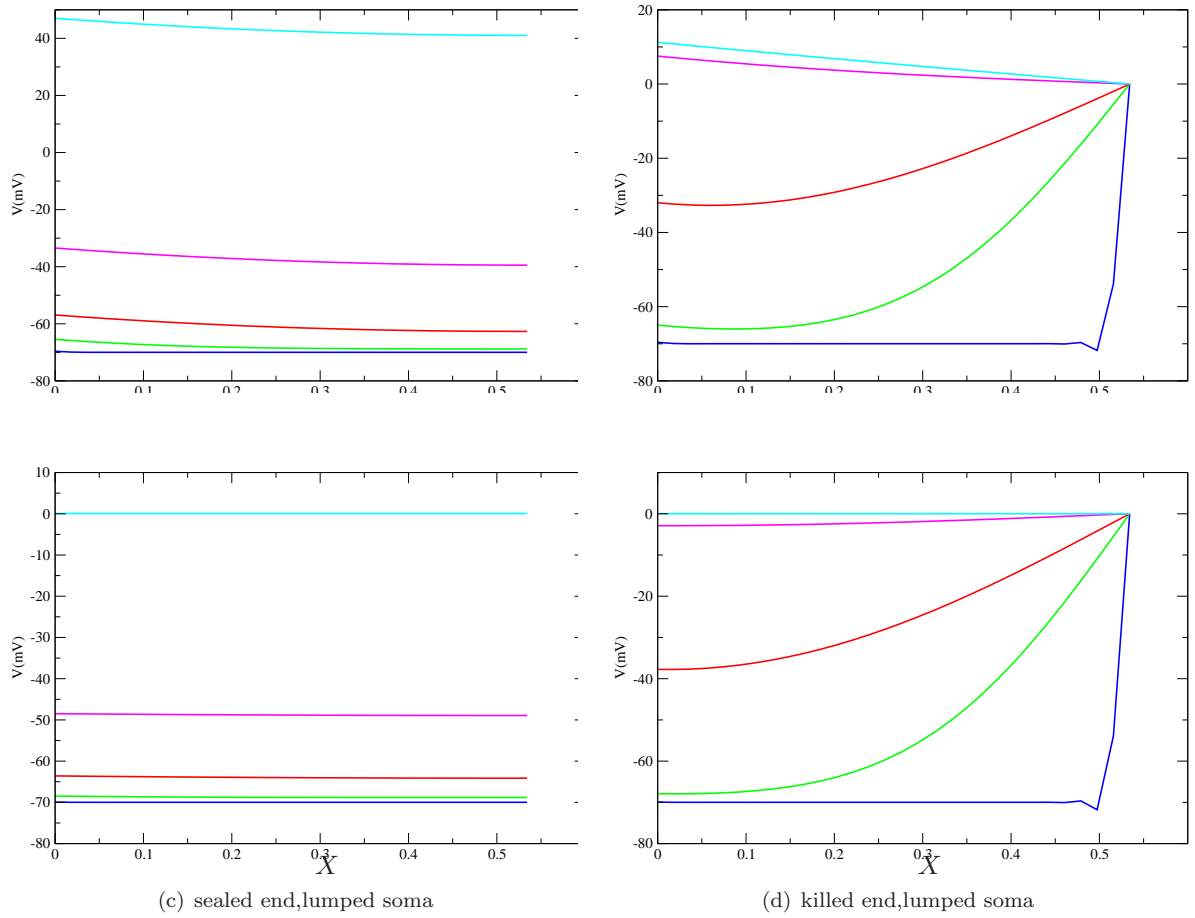


Figure 5. Evolution of voltage point and lumped soma, current injected at $i = 1$, —: $n = 1$; —: $n = 100$; —: $n = 500$; —: $n = 2000$; —: $n = 294670$

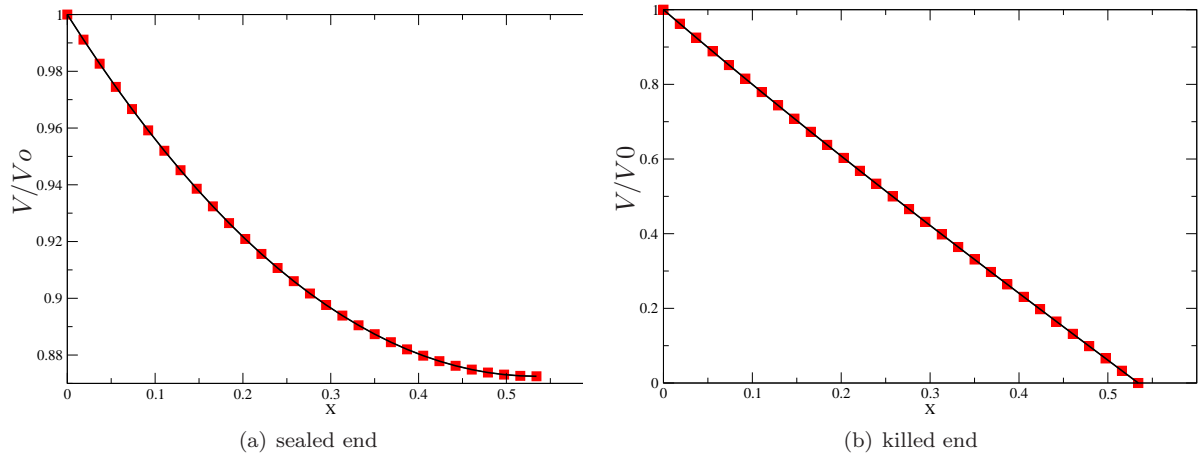


Figure 6. Comparison of compact scheme with analytical solution, sealed and killed end, point soma ■:compact;—:analytical

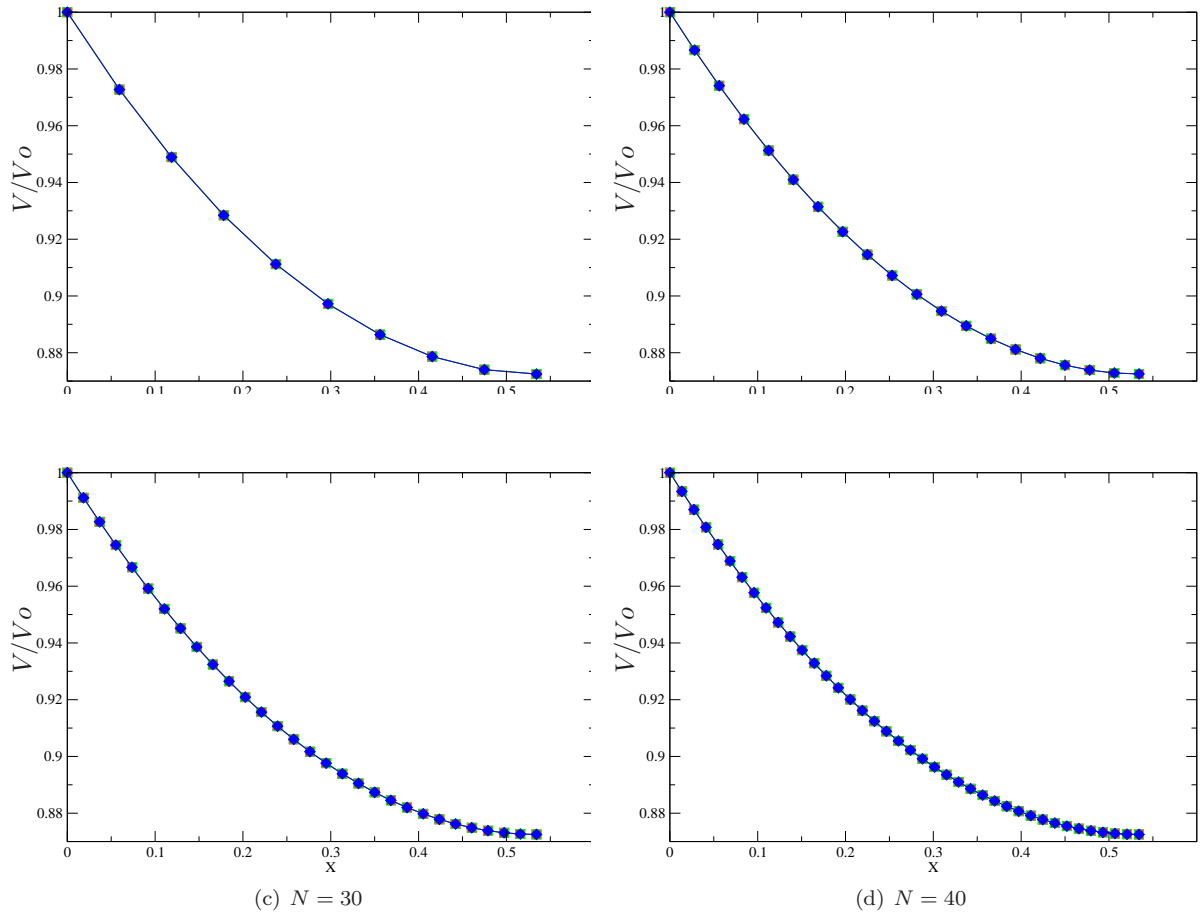


Figure 7. Comparison between compact, analytical and central difference schemes (point soma), $N = 10, 20, 30, 40$, ■:compact; ■:analytical; ■:central

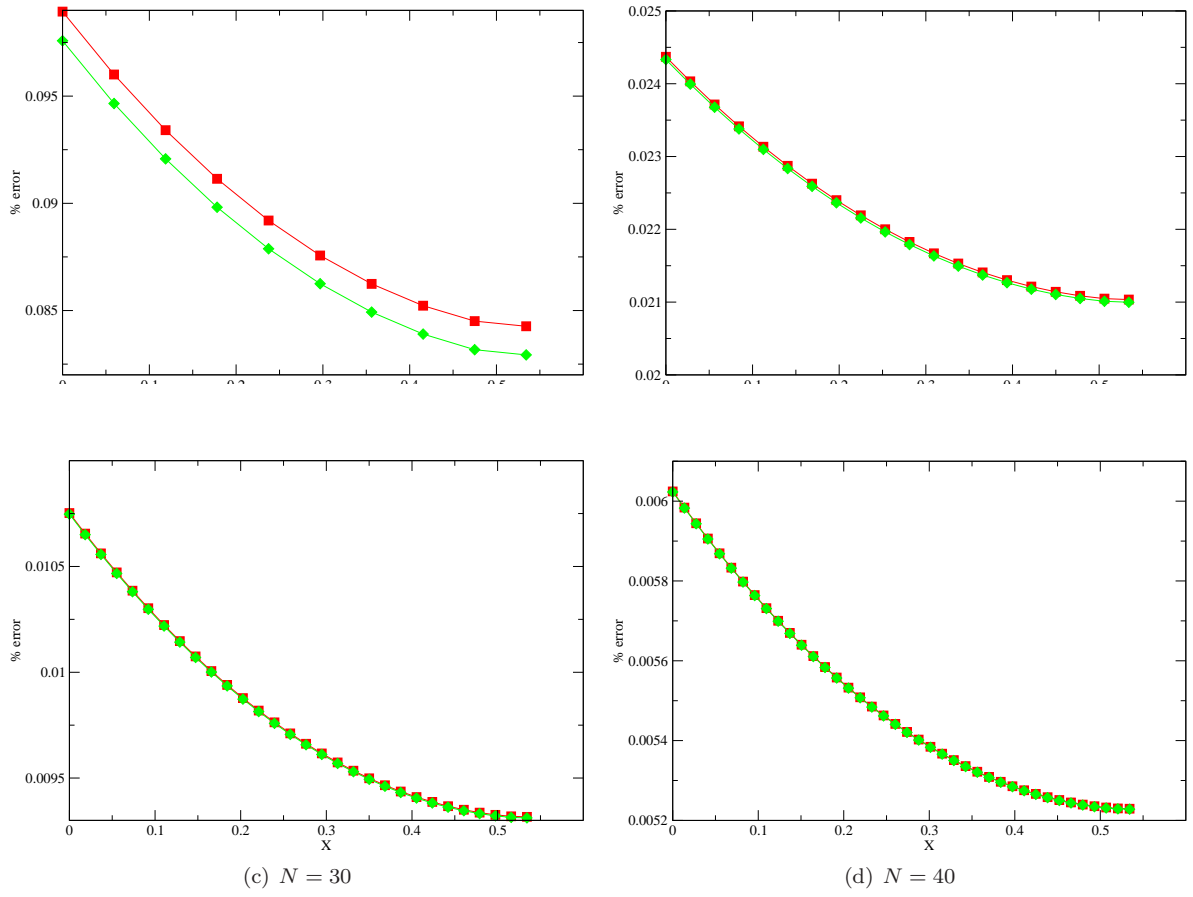


Figure 8. Comparison of error between compact and central difference schemes(point soma), $N = 10, 20, 30, 40$, ■:compact;◆:central

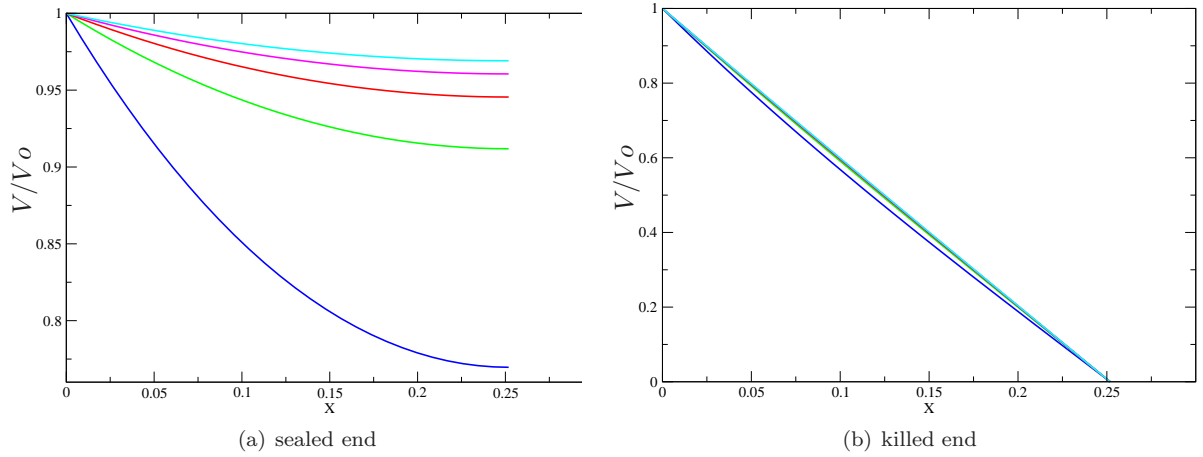


Figure 9. Effect of diameter, sealed and killed end,(point soma), —: $d = 1.85 \times 10^{-4}$ (cm); —: $d = 3 \times 1.85 \times 10^{-4}$; —: $d = 5 \times 1.85 \times 10^{-4}$; —: $d = 7 \times 1.85 \times 10^{-4}$; —: $d = 9 \times 1.85 \times 10^{-4}$

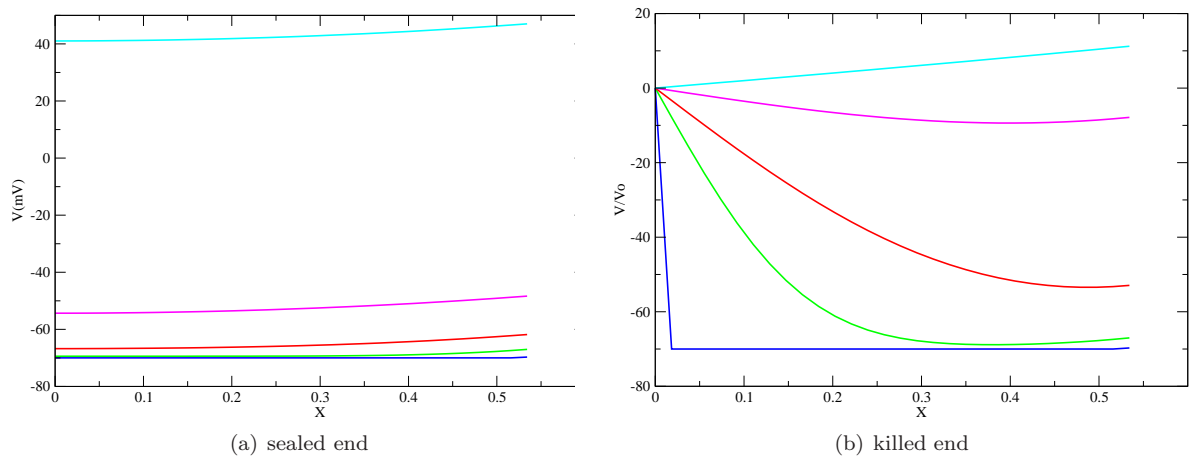


Figure 10. Evolution of voltage,current injected at $i = l$ (point soma), sealed end and killed end boundaries, —: $n = 1$; —: $n = 100$; —: $n = 500$; —: $n = 2000$; —: $n = 294670$

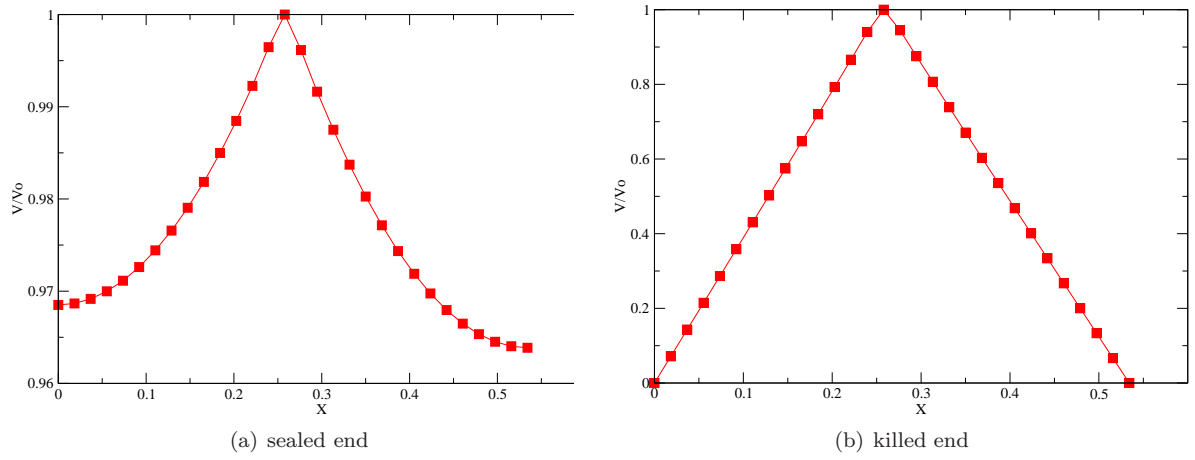


Figure 11. Current injected at $i = N/2$, (point soma) sealed end and killed end boundaries ■:compact

Tables

Table 1. Values of ΔT at various N

N	ΔT
10	$8.8088e - 04$
20	$1.9765e - 04$
30	$8.4841e - 05$
40	$4.6911e - 05$
80	$1.1433e - 05$

Table 2. Values of t in msec at various n

n	t
1	0.0016968
100	0.16968
500	0.84840
2000	3.3936
294670	500

Table 3. Parameters of dendrite used in simulation

Parameter	Values
length	400μ
diameter	$2 * 1.85\mu$
R_m	$20 * 10^3 \Omega.cm^2$
R_i	$330 \Omega.cm$
C_m	$1\mu farad/cm^2$
τ	20 msec
I_{inj}	0.1nanoamperes

Table 4. Comparison of percentage error (E_P) between compact and central for $N = 10$ (point soma)

Error	$i = 1$	$i = 2$	$i = 3$	$i = 4$	$i = 5$	$i = 6$	$i = 7$	$i = 8$	$i = 9$	$i = 10$
Compact	0.098941	0.096008	0.093412	0.091144	0.089198	0.087567	0.086244	0.085225	0.084506	0.084267
Central	0.097582	0.094655	0.092074	0.089819	0.087880	0.086251	0.084926	0.083901	0.083172	0.082929

Table 5. Resolving Efficiency ϵ of the second derivative schemes,([8], Table 5)

Scheme	$\epsilon = 0.1$	$\epsilon = 0.01$	$\epsilon = 0.001$
Fourth order central	0.59	0.31	0.17
Fourth order compact	0.68	0.39	0.22
Sixth order tridiagonal	0.80	0.55	0.38

Table 6. Values of λ (cm) at various d (cm)

d	λ
$1.85 * 10^{-4}$	0.052223
$3 * 1.85 * 10^{-4}$	0.091701
$5 * 1.85 * 10^{-4}$	0.11839
$7 * 1.85 * 10^{-4}$	0.14008
$9 * 1.85 * 10^{-4}$	0.15883